NSN 5962-01-197-8703

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individual manufactureer standards, etc.).

View Online at https://aerobasegroup.com/nsn/5962-01-197-8703

Body Length:
0.960 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1200.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and monolithic and hermetically sealed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-6 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-3.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Special Features:
Bitquantity type 4096; wordquantity type 1024
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards,
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Demilitarization:

Yes - demil/mli

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